

# KBPC5000 - KBPC5010

**PRV : 50 - 1000 Volts**  
**Io : 50 Amperes**

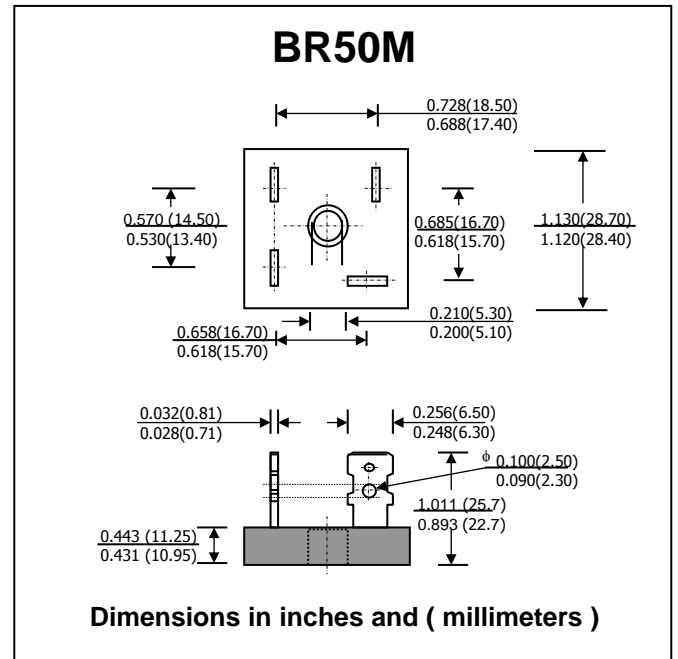
### FEATURES :

- \* High case dielectric strength
- \* High surge current capability
- \* High reliability
- \* High efficiency
- \* Low reverse current
- \* Low forward voltage drop
- \* **Pb / RoHS Free**

### MECHANICAL DATA :

- \* Case : Metal Case
- \* Epoxy : UL94V-0 rate flame retardant
- \* Terminals : plated .25" (6.35 mm). Faston
- \* Polarity : Polarity symbols marked on case
- \* Mounting position : Bolt down on heat-sink with silicone thermal compound between bridge and mounting surface for maximum heat transfer efficiency.
- \* Weight : 17.1 grams

# SILICON BRIDGE RECTIFIERS



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.  
 Single phase, half wave, 60 Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

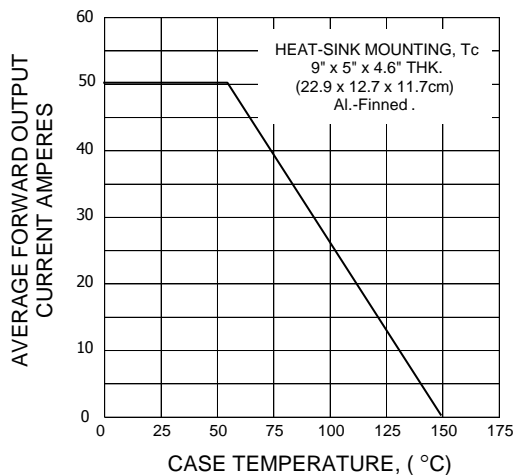
RATING	SYMBOL	KBPC 5000	KBPC 5001	KBPC 5002	KBPC 5004	KBPC 5006	KBPC 5008	KBPC 5010	UNIT
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Current Tc = 55°C	I <sub>F(AV)</sub>	50							A
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	400							A
Current Squared Time at t < 8.3 ms.	I <sup>2</sup> t	660							A <sup>2</sup> S
Maximum Forward Voltage per Diode at I <sub>F</sub> =25 A	V <sub>F</sub>	1.1							V
Maximum DC Reverse Current at Rated DC Blocking Voltage Ta = 25 °C Ta = 100 °C	I <sub>R</sub>	10							μA
	I <sub>R(H)</sub>	500							μA
Typical Junction Capacitance (Note 1)	C <sub>J</sub>	300							pF
Typical Thermal Resistance (Note 2)	RθJC	2.0							°C/W
Operating Junction Temperature Range	T <sub>J</sub>	- 40 to + 150							°C
Storage Temperature Range	T <sub>STG</sub>	- 40 to + 150							°C

**Note :**

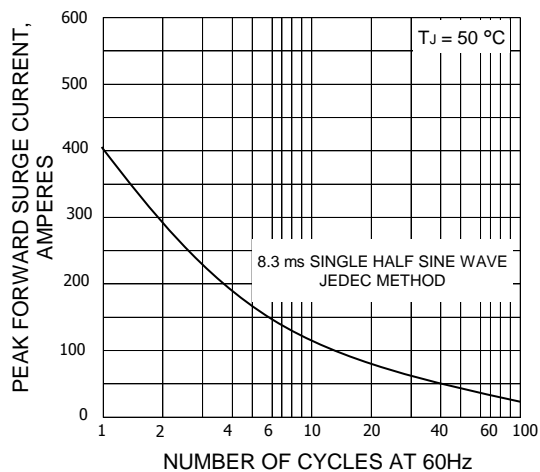
- ( 1 ) Thermal resistance from Junction to Case with units mounted on a 9"x5"x4.6" (22.9x12.7x11.7 cm) Al-Finned Heatsink.
- ( 2 ) Measured at 1.0 MHz and applied reverse volage of 4.0V DC.

### RATING AND CHARACTERISTIC CURVES (KBPC50000 - KBPC5010 )

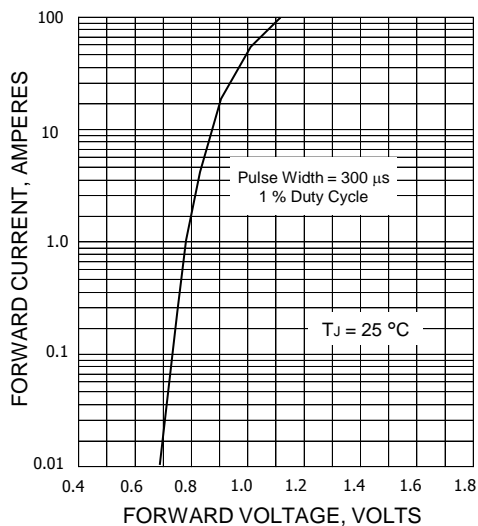
**FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT**



**FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT**



**FIG.3 - TYPICAL FORWARD CHARACTERISTICS PER DIODE**



**FIG.4 - TYPICAL REVERSE CHARACTERISTICS PER DIODE**

